

800MHz BAND MIXER GaAs MMIC

■GENERAL DESCRIPTION

NJG1555KB2 is a mixer GaAs MMIC features low distortion, high conversion gain and low noise figure.

NJG1555KB2 includes a mixer and a local amplifier, and ideally suitable for 800MHz band digital mobile phone handsets.

An ultra small & ultra thin FLP6-B2 package is adopted.

■PACKAGE OUTLINE

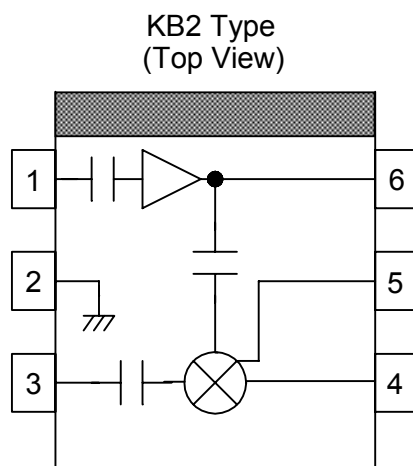


NJG1555KB2

■FEATURES

- | | | |
|-----------------------------------|--------------------------------------|---|
| ●Low voltage operation | +2.7V | |
| ●High conversion gain | 12dB typ. | @ $f_{RF}=820\text{MHz}$, $P_{LO}=-15\text{dBm}$ |
| ●High Input IP3 | +1.0dBm typ. | @ $f_{RF}=820.0+820.1\text{MHz}$, $P_{LO}=-15\text{dBm}$ |
| ●Low noise figure | 5.0dB typ. | @ $f_{RF}=820\text{MHz}$, $P_{LO}=-15\text{dBm}$ |
| ●Ultra small & ultra thin package | FLP6-B2 (Mount Size: 2.1x2.0x0.75mm) | |

■PIN CONFIGURATION



Pin Connection

1. LOIN
2. GND
3. RFIN
4. IFOUT
5. BPC
6. VLO

NOTE: The portion above shows orientation mark printed on the package surface.

NOTE: Please note that any information on this catalog will be subject to change.

NJG1555KB2

■ABSOLUTE MAXIMUM RATINGS

($T_a=25^{\circ}\text{C}$, $Z_s=Z_l=50\Omega$)

PARAMETERS	SYMBOL	CONDITIONS	RATINGS	UNITS
Mixer Supply Voltage	V_{MIX}		5	V
Local Amplifier Supply Voltage	V_{LO}		5	V
Mixer RF Input Power	P_{RFIN}	$V_{\text{MIX}}=2.7\text{V}$, $V_{\text{LO}}=2.7\text{V}$	10	dBm
Mixer LO Input Power	P_{LOIN}	$V_{\text{MIX}}=2.7\text{V}$, $V_{\text{LO}}=2.7\text{V}$	10	dBm
Power Dissipation	P_{D}		450	mW
Operating Temperature	T_{opr}		-40~+85	$^{\circ}\text{C}$
Storage Temperature	T_{stg}		-55~+125	$^{\circ}\text{C}$

■ELECTRICAL CHARACTERISTICS

GENERAL CONDITIONS: $T_a=25^{\circ}\text{C}$, $V_{\text{MIX}}=2.7\text{V}$, $V_{\text{LO}}=2.7\text{V}$, $f_{\text{RF}}=820\text{MHz}$, $f_{\text{LO}}=690\text{MHz}$

$P_{\text{RF}}=-30\text{dBm}$, $P_{\text{LO}}=-15\text{dBm}$, $Z_s=Z_l=50\Omega$, with test circuit

PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Operating Frequency	freq		800	820	900	MHz
Mixer Supply Voltage	V_{MIX}		2.5	2.7	4.5	V
Local Amplifier Supply Voltage	V_{LO}		2.5	2.7	4.5	V
Mixer Current	I_{MIX}	$P_{\text{RF}}=\text{OFF}$, $P_{\text{LO}}=\text{OFF}$	-	5.0	7.0	mA
Local Amplifier Current	I_{LO}	$P_{\text{RF}}=\text{OFF}$, $P_{\text{LO}}=\text{OFF}$	-	1.0	1.6	mA
Conversion Gain	G_{C}		10.0	12.0	-	dB
Input 3rd Order Intercept point	IIP3	$f_{\text{RF}}=820.0\text{MHz}+820.1\text{MHz}$	-1.0	+1.0	-	dBm
Noise Figure	NF		-	5.0	6.0	dB
LO to RF Isolation	ISL	IF OUT Port: 50Ω term.	-	9.0	-	dB

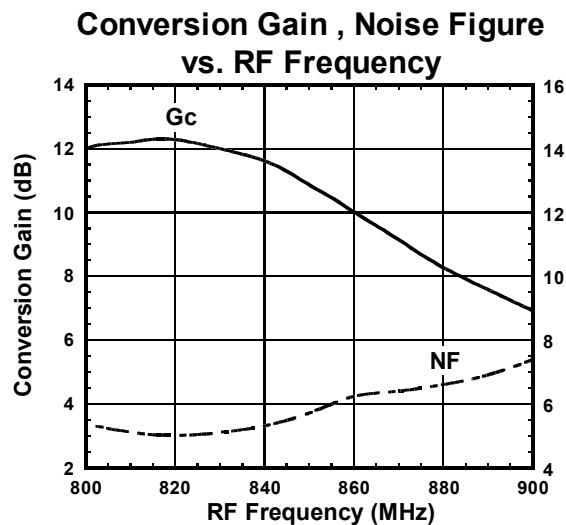
■ TERMINAL INFORMATION

PIN No.	SYMBOL	DESCRIPTIONS
1	LOIN	Local power input terminal of local amplifier. External matching circuit is required.
2	GND	Ground terminal (0V).
3	RFIN	RF input terminal of mixer. External matching circuit is required.
4	IFOUT	IF signal output terminal for mixer external matching circuit is required. Please connect mixer power supply through choke inductor (L6) as shown in test circuit.
5	BPC	Optional bypass capacitor terminal for mixer. Please connect optimum capacitor if need for tuning Gc or IP3.
6	VLO	Local amplifier supply terminal. Please place R1 & L4 close to this terminal as shown in test circuit.

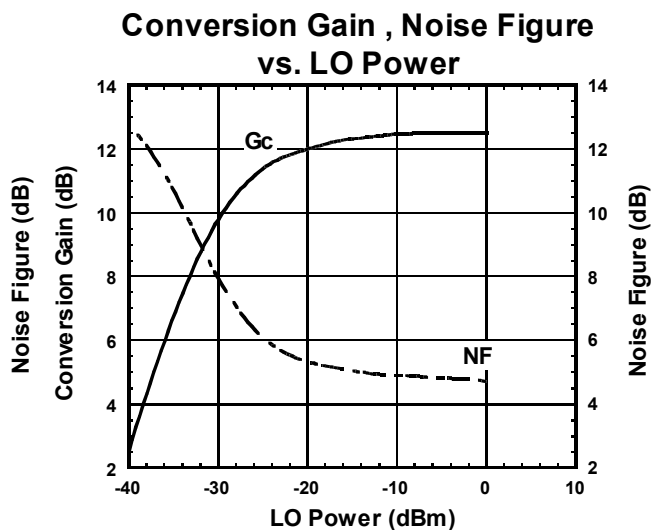
NOTE:

- 1) Ground terminal (2pin) should be connected with ground plane by multiple via holes for good grounding.

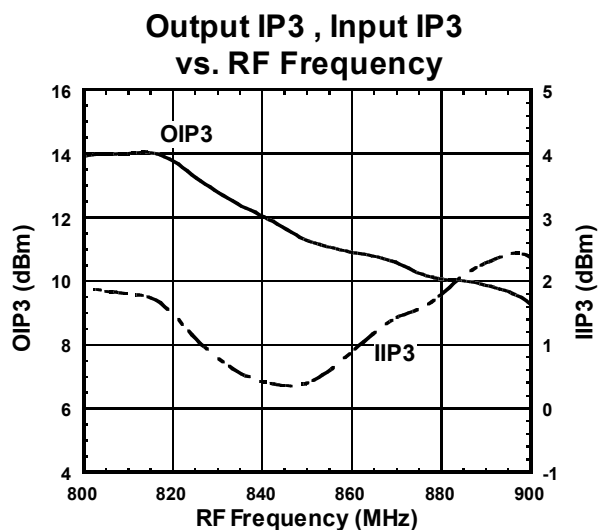
■ TYPICAL CHARACTERISTICS ($f_{LO}=690\text{MHz}$)



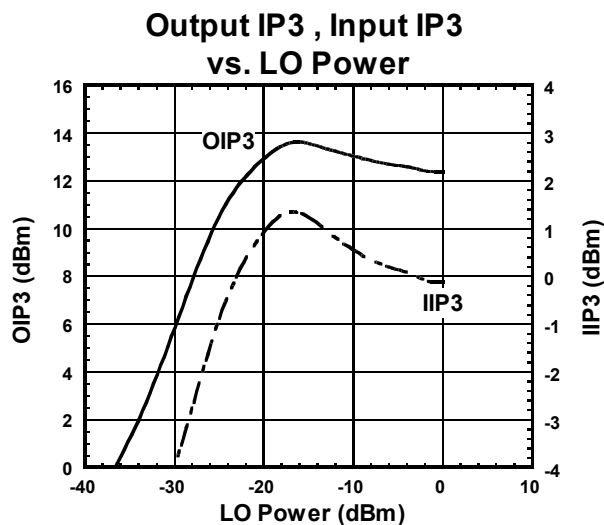
Condition
 $f_{IF}=130\text{MHz}$
 $f_{RF}=800\sim 900\text{MHz}$, $P_{RF}=-30\text{dBm}$
 $f_{LO}=670\sim 770\text{MHz}$, $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=2.7\text{V}$



Condition
 $f_{IF}=130\text{MHz}$
 $f_{RF}=820\text{MHz}$, $P_{RF}=-30\text{dBm}$
 $f_{LO}=690\text{MHz}$
 $V_{MIX}=V_{LO}=2.7\text{V}$



Condition
 $f_{IF}=130\text{MHz}$
 $f_{RF1}=800\sim 900\text{MHz}$, $P_{RF}=-30\text{dBm}$
 $f_{RF2}=f_{RF1}+100\text{kHz}$
 $f_{LO}=670\sim 770\text{MHz}$, $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=2.7\text{V}$

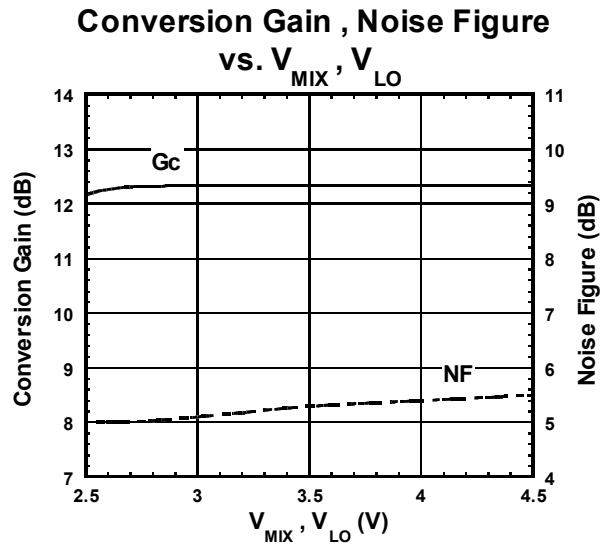


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 $f_{LO}=690\text{MHz}$
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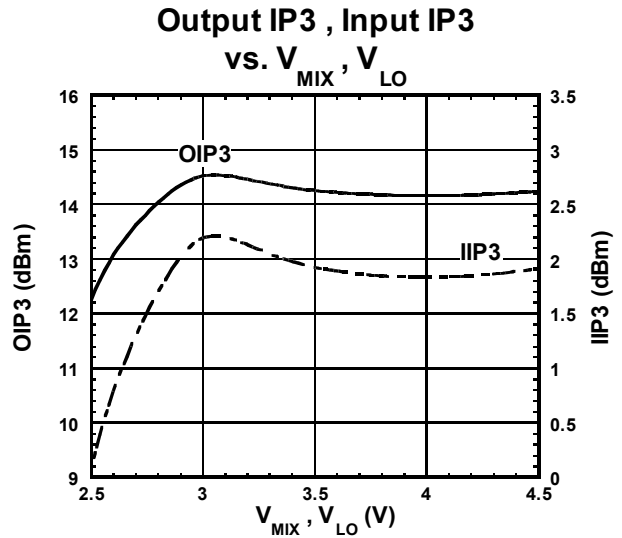
$$OIP3 = \frac{3X_{IF}-IM3}{2}$$

$$IIP3 = OIP3 - G_c$$

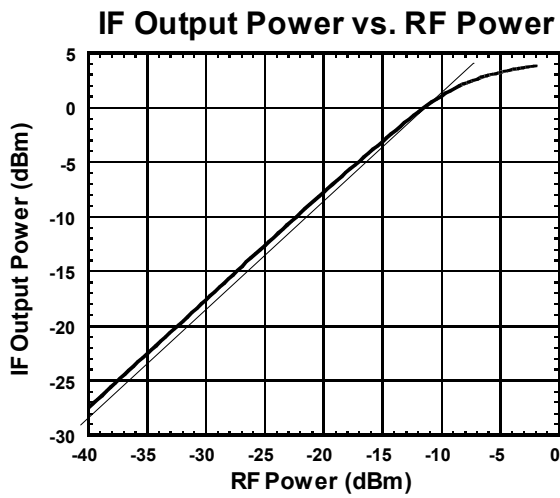
TYPICAL CHARACTERISTICS (Continued)



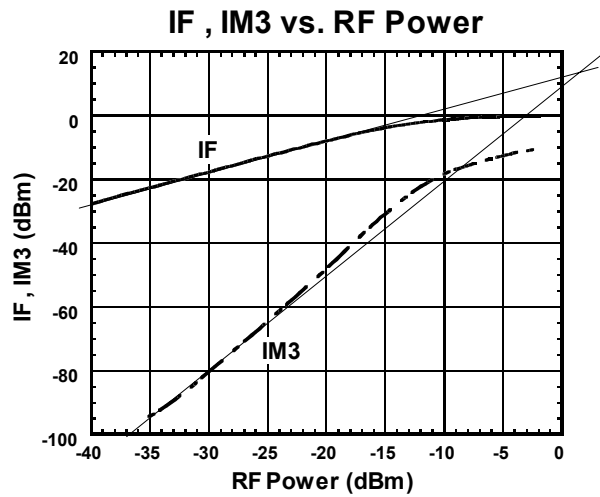
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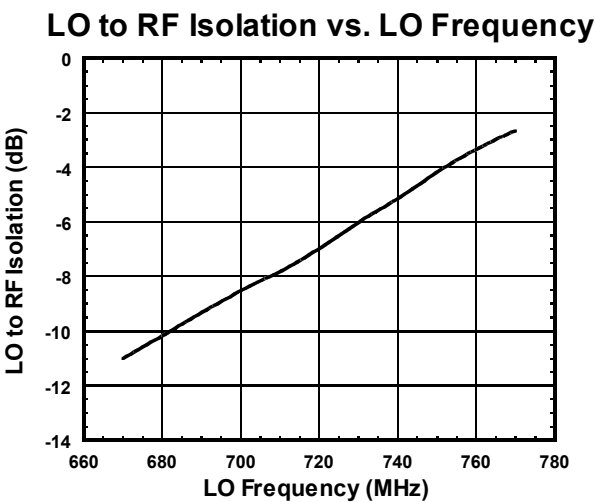


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 $f_{LO}=690\text{MHz}$, $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=2.7\text{V}$

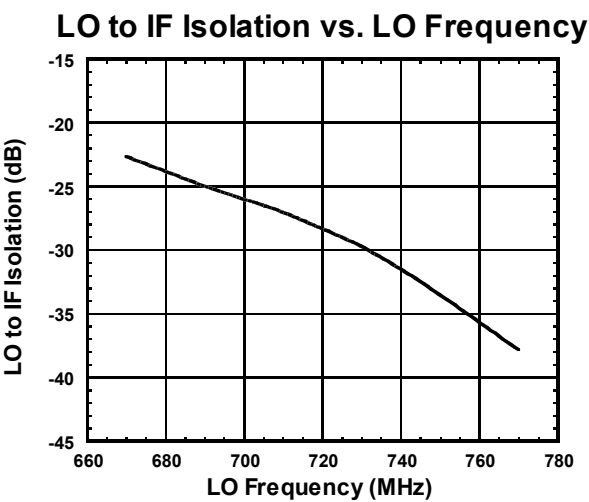


Condition
 $f_{IF}=130\text{MHz}$
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 $f_{LO}=690\text{MHz}$, $P_{LO}=-15\text{dBm}$
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■TYPICAL CHARACTERISTICS (Continued)



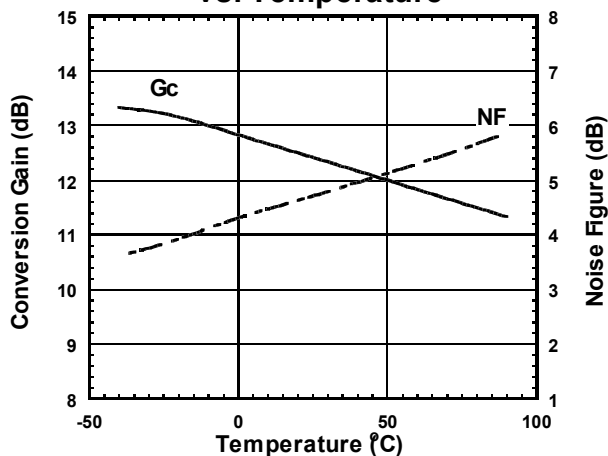
Condition
 $f_{LO}=670\sim 770\text{MHz}$
 $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=2.7\text{V}$
IF OUT Port: 50Ω term.



Condition
 $f_{LO}=670\sim 770\text{MHz}$
 $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=2.7\text{V}$
RF IN Port: 50Ω term.

TYPICAL CHARACTERISTICS (Continued)

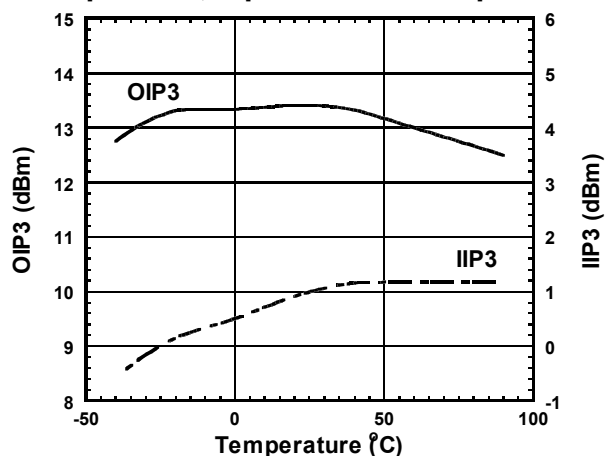
Conversion Gain , Noise Figure vs. Temperature



Condition

$f_{IF}=130\text{MHz}$
 $f_{RF}=820\text{MHz}$, $P_{RF}=-30\text{dBm}$
 $f_{LO}=690\text{MHz}$, $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=2.7\text{V}$

Output IP3 , Input IP3 vs. Temperature

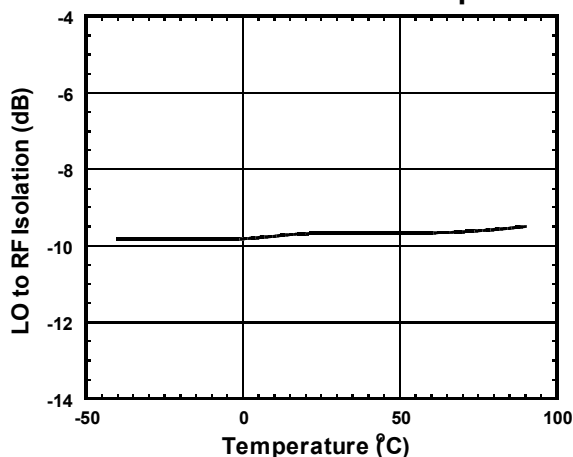


Condition

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 $f_{RF}=820.0+820.1\text{MHz}$
 $P_{RF}=-30\text{dBm}$
 $f_{LO}=690\text{MHz}$, $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=2.7\text{V}$

$OIP3 = \frac{3XIF-IM3}{2}$
 $IIP3 = OIP3 - G_c$

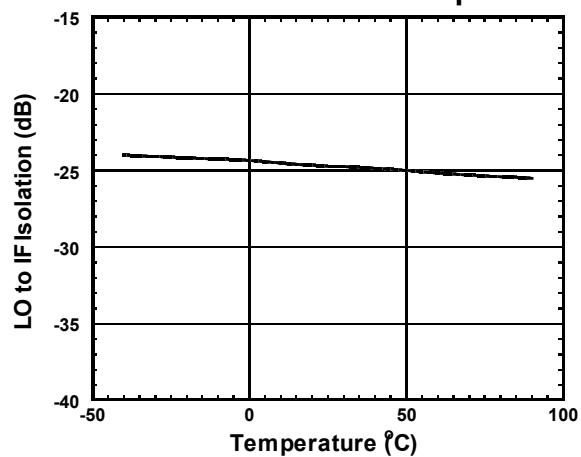
LO to RF Isolation vs. Temperature



Condition

$f_{LO}=690\text{MHz}$
 $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=2.7\text{V}$
 IF OUT Port: 50Ωterm.

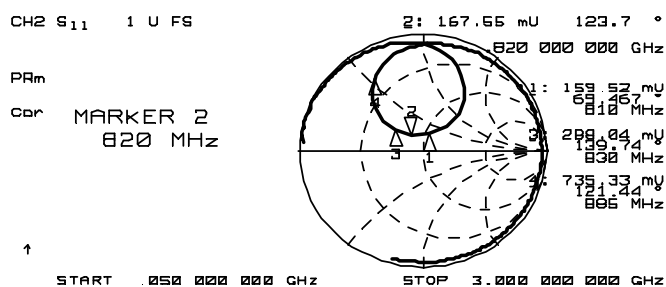
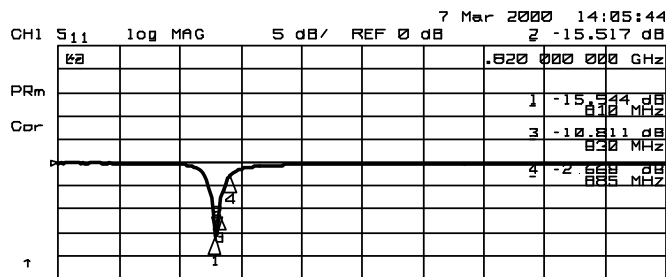
LO to IF Isolation vs. Temperature



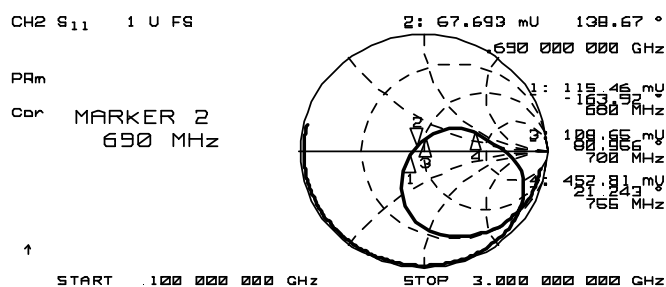
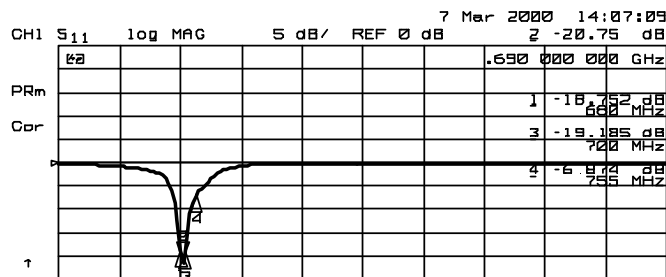
Condition

$f_{LO}=690\text{MHz}$
 $P_{LO}=-15\text{dBm}$
 $V_{MIX}=V_{LO}=2.7\text{V}$
 RF IN Port: 50Ωterm.

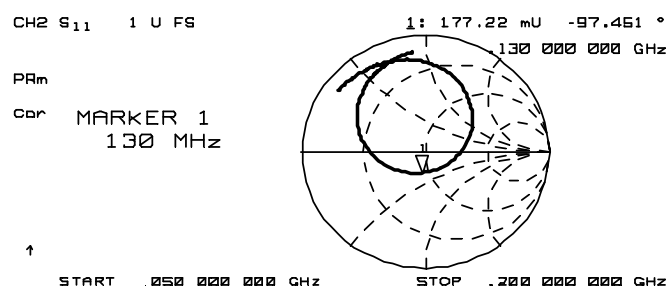
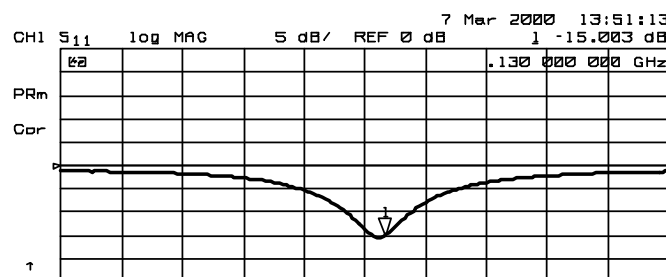
TYPICAL CHARACTERISTICS (Continued)



RF IN Port Impedance
(LOCAL IN Port, IF OUT Port : 50Ω term.)

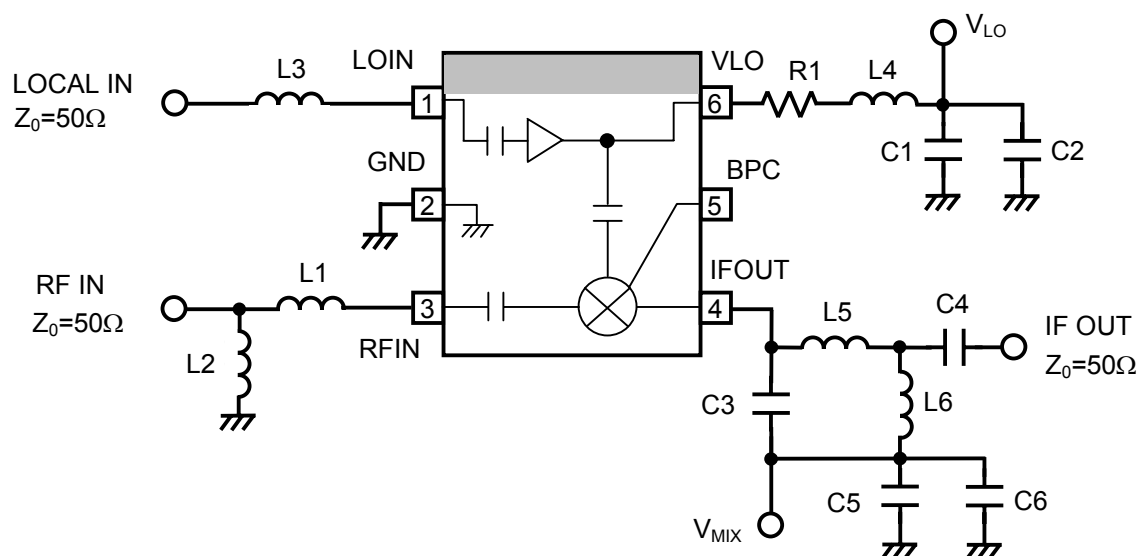


LOCAL IN Port Impedance
(RF IN Port, IF OUT Port : 50Ω term.)



IF OUT Port Impedance
(RF IN Port, LOCAL IN Port : 50Ω term.)

APPLICATION CIRCUIT

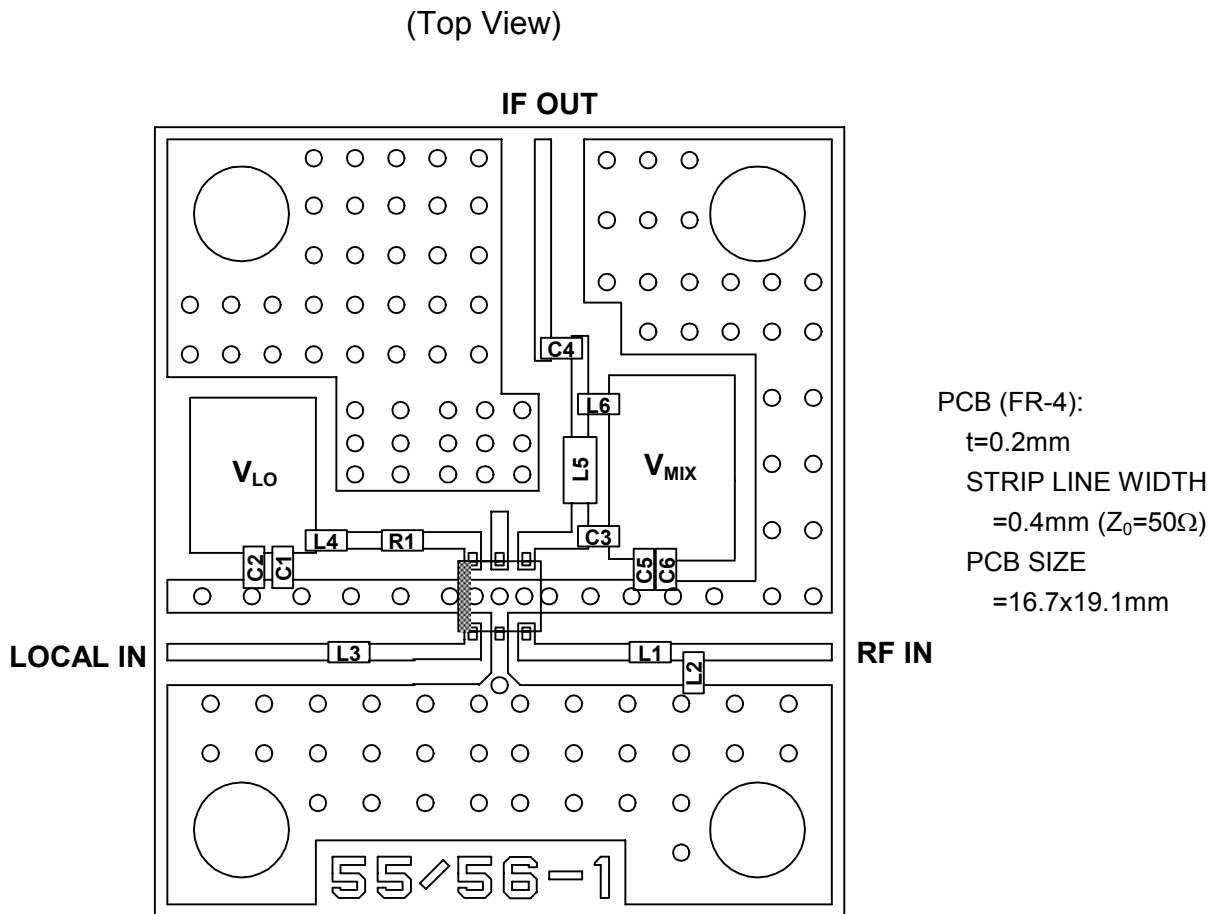


PARTS LIST

PARTS ID	800MHz Band		COMMENT
	Lower LOCAL	Upper LOCAL	
	$f_{LO}=690\text{MHz}$ $f_{IF}=130\text{MHz}$	$f_{LO}=950\text{MHz}$ $f_{IF}=130\text{MHz}$	
L1	15nH	15nH	TAIYO-YUDEN (HK1005)
L2	3.9nH	3.9nH	TAIYO-YUDEN (HK1005)
L3	47nH	27nH	TAIYO-YUDEN (HK1005)
L4	39nH	22nH	TAIYO-YUDEN (HK1005)
L5	120nH	120nH	TAIYO-YUDEN (HK1608)
L6	56nH	56nH	TAIYO-YUDEN (HK1005)
C1	100pF	100pF	MURATA (GRM36)
C2	1000pF	1000pF	MURATA (GRM36)
C3	9pF	9pF	MURATA (GRM36)
C4	1000pF	1000pF	MURATA (GRM36)
C5	10pF	10pF	MURATA (GRM36)
C6	1000pF	1000pF	MURATA (GRM36)
R1	27Ω	22Ω	1005 Size

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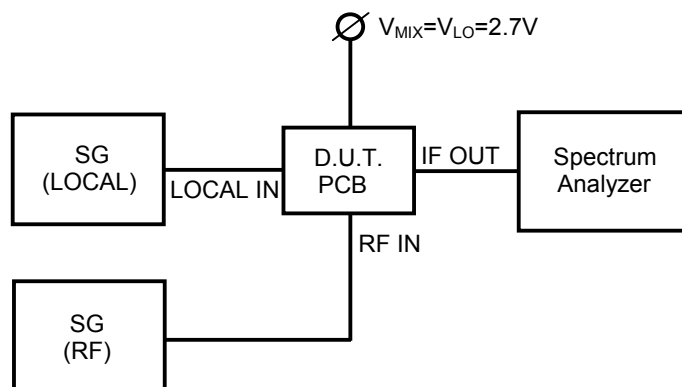
RECOMMENDED PCB DESIGN



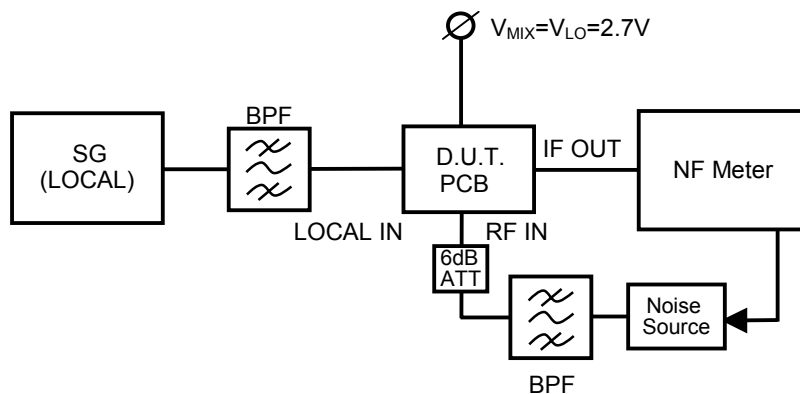
PRECAUTIONS

- [1] Please locate L4 and R1 close to VLO terminal (6).
- [2] Please locate C1 and C2 close to L4.
- [3] Please locate C5 and C6 close to C3.

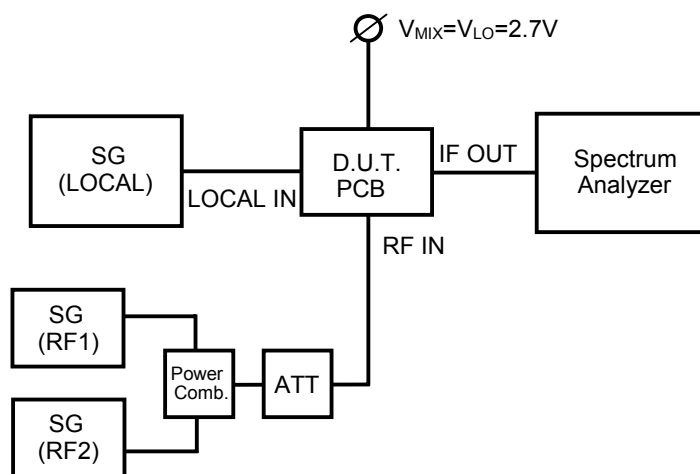
MEASURING BLOCK DIAGRAM



Conversion Gain Measuring Block Diagram



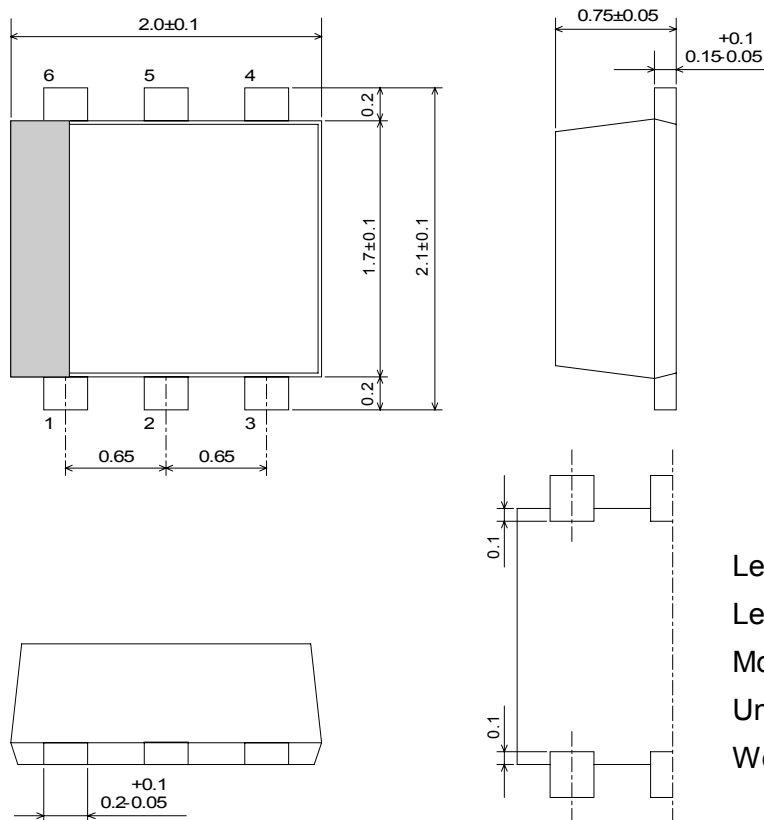
Noise Figure Measuring Block Diagram



OIP3, IIP3 Measuring Block Diagram

NJG1555KB2

■PACKAGE OUTLINE (FLP6-B2)



Lead material	: Copper
Lead surface finish	: Solder plating
Molding material	: Epoxy resin
Unit	: mm
Weight	: 6.5mg

Cautions on using this product

This product contains Gallium-Arsenide (GaAs) which is a harmful material.

- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle with care to avoid these damages.

[CAUTION]

The specifications on this databook are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

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Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

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Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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